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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/810,619	03/29/2004	Hung-Wen Su	0941-0938PUS1	9827
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PO BOX 747			MACARTHUR, SYLVIA	
FALLS CHURC	CH, VA 22040-0747		ART UNIT	PAPER NUMBER
	`	1763		
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SHORTENED STATUTORY	PERIOD OF RESPONSE	NOTIFICATION DATE	DELIVERY MODE	
3 MON	THS	02/14/2007	ELECTRONIC	

Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

Notice of this Office communication was sent electronically on the above-indicated "Notification Date" and has a shortened statutory period for reply of 3 MONTHS from 02/14/2007.

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mailroom@bskb.com

	Application No.	Applicant(s)				
	10/810,619	SU ET AL.	·			
Office Action Summary	Examiner	Art Unit				
	Sylvia R. MacArthur	1763				
The MAILING DATE of this communication a Period for Reply	oppears on the cover sheet with th	e correspondence	address			
A SHORTENED STATUTORY PERIOD FOR REF WHICHEVER IS LONGER, FROM THE MAILING - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication If NO period for reply is specified above, the maximum statutory peric - Failure to reply within the set or extended period for reply will, by stat Any reply received by the Office later than three months after the ma earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNICAT 1.136(a). In no event, however, may a reply but will apply and will expire SIX (6) MONTHS to tute, cause the application to become ABANDO	ION. e timely filed from the mailing date of this DNED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 11	<u>/28/2006</u> .					
2a)⊠ This action is FINAL . 2b)□ TI	his action is non-final.					
3) Since this application is in condition for allow	3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice unde	r Ex parte Quayle, 1935 C.D. 11	, 453 O.G. 213.				
Disposition of Claims						
4) Claim(s) 1-31 is/are pending in the application	on.					
4a) Of the above claim(s) is/are withd	rawn from consideration.					
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>1-31</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and	d/or election requirement.					
Application Papers						
9)☐ The specification is objected to by the Exami	iner.					
10)⊠ The drawing(s) filed on 29 March 2004 is/are						
Applicant may not request that any objection to the						
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the	* * * * * * * * * * * * * * * * * * * *	•	- ·			
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for forei a) All b) Some * c) None of:	gn priority under 35 U.S.C. § 119	9(a)-(d) or (f).				
1.☐ Certified copies of the priority docume	ents have been received					
2. Certified copies of the priority docume		cation No				
3. Copies of the certified copies of the pr			al Stage			
application from the International Bure	•					
* See the attached detailed Office action for a li	ist of the certified copies not rece	eived.				
Attachment(s)	_					
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summ Paper No(s)/Ma					
Notice of Draitsperson's Patent Drawing Review (P10-946) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0 Paper No(s)/Mail Date		al Patent Application (F	PTO-152)			

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

2. Claim 1 is rejected under 35 U.S.C. 102(b) as being anticipated by Masayuki et al (JP 02-014512)

Masayuki et al teaches a resist removal apparatus for a semiconductor wafer. The apparatus of Masayuki et al comprises a bath tank 12, a rotatable wafer chuck 11, and a sliding element 10 (s up/down arrows shows 10 can slide), see Fig. 1

Regarding the claim limitation that the wafer be covered with a metal layer: This is a matter of an intended and is not given patentable weight as the inclusion of a wafer or article worked upon by a structure being claimed does not impart patentability to the claims. In re Young, 75 F.2d 966, 25 USPQ 69 (CCPA 1935) (as restated in In re Otto, 312 F. 2d 937, 136 USPQ 458, 459 (CCPA 1963)).

Regarding the claim limitation that a bath tank contain a chemical bath for a metal etchant: The apparatus of Masuyuki et al is provided with a tank (containing a treatment solution) that is structurally and inherently capable of containing a metal etching solution. Note Masuyuki et al does teach that apparatus removes a layer from the peripheral edge, see English Translation of the Abstract. The type of layer removed is a matter of intended use.

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3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 2-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Masayuki et al (JP 02-014512) al in view of Berdan et al (US 3,898,095).

Regarding claims 2 and 4: Masayuki et al fails to teach a front suppression line.

Berdan et al teaches a method of etching aluminum.

Berdan et al teaches a manifold pipe 22 (front suppression line and auxillary lines).

Berdan et al teaches in col.3 lines 43-48 the motivation to provide the front suppression line is to rinse the etchant from the front of the substrate.

Regarding claim 6: Berdan et al illustrates Fig.1 Manifold pipes 22 are placed along the wafer.

Regarding claims 8, 10, and 12: Rear suppression line 22 illustrated in Fig.1. The apparatus comprised a rear rinse line disposed behind the wafer

The motivation to provide the rinse lines of Berdan along the substrate is allow for more uniform etching of the substrate. Thus, it would have been obvious for one of ordinary skill in the art at the time of the claimed invention to provide front and rear suppression lines in the apparatus of Masayuki et al in order to better control the localization of etching to the edge of the wafer while providing a treatment fluid of the front and rear surfaces of the wafer.

Regarding claims 3,5,7,9, 11, and 13: The rinsing apparatus of Berdan et al (element 22) fails to teach supplying the gas at the recited flow rate. Where the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by

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routine experimentation. It would have been obvious for one of ordinary skill in the art at the time of the claimed invention to determine the optimum values of the relevant process parameters through routine experimentation in the absence of a showing of a criticality. In re Aller, 220 F. 2d 454, 456, 105 USPQ 233, 235 (CCPA 1955)).

Thus it would have been obvious for one of ordinary skill in the art at the time of the claimed invention to introduce a rinsing fluid in the recited range in order to provide an optimal flow rate, and thus provide a more consistent and uniform manufacturing process.

5. Claims 14, 15, 24, and 26-31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Masayuki et al in view of Brown et al (US 2003/0209255).

The teachings of Masayuki et al were discussed above.

Regarding claim 14: Masayuki et al fails to teach that the wafer has a metal layer.

Brown et al teaches an etching apparatus wherein the Wafer W comprises a copper layer. The prior art of Brown et al teaches that etching of metal layers is conventional by teaching the specific type of wafer used in the apparatus. Thus, it would have been obvious for one of ordinary skill in the art at the time of the claimed invention to use the substrate of Brown et al in the apparatus of Masayuki et al to etch the edge of the wafer that comprises a metal layer.

Regarding claim 15: All fail to teach the location of the portion is a specific dimension from the wafer edge. However, the apparatus resulting from the modification of the apparatus of Beretta et al with those of Brown et al is obvious capable of removing this range according to In Gardner v.

TEC Systems, Inc., 725 F.2d 1338, 220 USPQ 777 (Fed. Cir. 1984), cert. denied, 469 U.S. 830, 225 USPQ 232 (1984), the Federal Circuit held that, where the only difference between the prior art and the claims was a recitation of relative dimensions of the claimed device and a device

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having the claimed relative dimensions would not perform differently than the prior art device, the claimed device was not patentably distinct from the prior art device. Thus, it would have been obvious for one of ordinary skill in the art at the time of the claimed invention to remove the portion of the wafer layer in the range as recited in clam 15.

Regarding claim 24: Brown et al teaches that the metal layer is Cu in [0011].

Regarding claim 26: See the illustration of Fig.1 of Masayuki et al.

Regarding claims 27-30: Masayuki et al holds the backside of the wafer and rotates the backside, see Figs. 1 and 2.

6. Claims 16-22 are rejected under 35 U.S.C. 103(a) as being unpatentable over Masayuki et al in view of Brown et al as applied to claims 14, 15, 24, and 26 above, and further in view of Berdan et al.

The teachings of the primary references modified by Masayuki et al were discussed above.

The modification fails to teach a front suppression or rinse flow.

Berdan et al teaches a method of etching aluminum.

Berdan et al teaches a manifold pipe 22 (front suppression line and rinse lines).

Berdan et al teaches in col.3 lines 43-48 that the front suppression line is used to rinse the etchant from the front of the substrate.

Berdan et al illustrates Fig.1 Manifold pipes 22 are placed along the wafer.

Thus, it would have been obvious for one of ordinary skill in the art at the time of the claimed invention to provide a rinse and suppression in the apparatus of the primary references modified

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by Brown et al to keep the etching from splashing on the wafer and to ensure that the wafer rinsed prior to the next processing step as taught by Berdan et al.

7. Claim 23 is rejected under 35 U.S.C. 103(a) as being unpatentable over Masayuki et al in view of Ching et al.

The teachings of Beretta et al were discussed above. Beretta et al fails to teach the speed of rotation of the wafer.

Ching et al teaches a ferris wheel like stripping or cleaning mechanism, see abstract and Figs. 3B,4B, 5B and 6B. Wafers 306 are held in a vertical orientation by holder 308 see col. 3 line 48-col.4 line 9.Col. 3 lines 32-47

Ching teaches that the wafer is rotated between 0.5 and 100 RPM see col.4 lines 25-29. The speed of rotation of the spinning wafer is an optimizable parameter that would affect the throughput of the cleaning process. Where the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation. It would have been obvious for one of ordinary skill in the art at the time of the claimed invention to determine the optimum values of the relevant process parameters through routine experimentation in the absence of a showing of a criticality. In re Aller, 220 F. 2d 454, 456, 105 USPQ 233, 235 (CCPA 1955)). Thus, it would have been obvious for one of ordinary skill in the art at the time of the claimed invention to design the apparatus of Beretta et al to rotate the wafer at the speed taught by Ching et al.

8. Claim 25 is rejected under 35 U.S.C. 103(a) as being unpatentable over Masayuki et al in view of Brown et al as applied to claims 14, 15, 24, and 26 above, and further in view of Dunn (US 6,539,963).

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The teachings of Masayuki et al in view of Brown et al were discussed above.

The resulting combination fails to teach a bath comprising a solution of sulfuric acid, hydrogen peroxide, and DI water.

Dunn teaches a wet processing system 10 filled with "Piranha" which is a mixture of sulfuric acid, hydrogen peroxide, and DI water see col.4 lines 32-38. Dunn notes that the type of etchant mixture used is based upon the type wafer used and the desired processing result.

Thus, it would have been obvious for one of ordinary skill in the art at the time of the claimed invention to provide a Piranha solution as the etchant mixture.

9. Claim 23 is rejected under 35 U.S.C. 103(a) as being unpatentable over Masayuki et al in view of Brown et al as applied to claims 14, 15, 24, and 26 above, and further in view of Erk et al (US 5,593,505).

The teachings of Masayuki et al in view of Brown et al were discussed above.

The resulting combinations fail to teach a wafer rotated at a speed of 5 to 300 rpm.

Erk et al teaches a method and apparatus of wet etching wherein a wafer is rotated.

According to col.6 lines 15-20 the wafer is rotated at 8 rpm and preferably 12 and 18 rpm.

The rotation speed is an optimizable parameter. The motivation to combine the teachings of Erk et al in the method of Masayuki et al modified by Brown et al is that the rotational speed of Erk et al will result in a more uniformly processed wafer.

Response to Arguments

10. Applicant's arguments with respect to claims 1 and 14 have been considered but are unpersuasive. Regarding the argument that the wafer edge of Masyayuki et al is not be covered with a metal layer: This is a matter of an intended and is not given patentable weight as the

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inclusion of a wafer or article worked upon by a structure being claimed does not impart patentability to the claims. In re Young, 75 F.2d 966, 25 USPO 69 (CCPA 1935) (as restated in In re Otto, 312 F. 2d 937, 136 USPQ 458, 459 (CCPA 1963)).

Regarding the claim limitation that the bath tank of Masayuki et al does not contain a chemical bath for a metal etchant: The apparatus of Masuyuki et al is provided with a tank (containing a treatment solution) that is structurally and inherently capable of containing a metal etching solution. Note Masuyuki et al does teach that apparatus removes a layer from the peripheral edge, see English Translation of the Abstract. The type of layer removed is a matter of intended use.

Conclusion

11. THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

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12. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Sylvia R. MacArthur whose telephone number is 571-272-1438. The examiner can normally be reached on M-F during the hours of 8:30 a.m. and 5 p.m.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Parviz Hassanzadeh can be reached on 571-272-1435. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Sylvia R MacArthur Patent Examiner Art Unit 1763

February 7, 2007